

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Extended temperature range T_i = 175 °C
- Side wettable flanks for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 1 kV HBM (class H1C)
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- DC to DC conversion
- High-speed line driver
- High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C	-	-	-20	V
V _{GS}	gate-source voltage		-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{sp} = 25 °C	-	-	-18	А
P _{tot}	total power dissipation	T _{sp} = 25 °C	-	-	19	W
Static chara	acteristics					
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -6 A; T _j = 25 °C	-	30	38	mΩ



5. Pinning information

Table 2	. Pinning info	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G ↓ ↓ ↓ ↓
4	S	source	3 8 4	
5	D	drain	Transparent top view	
6	D	drain	DFN2020MD-6 (SOT1220)	s
7	D	drain		017aaa259
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BUK4D38-20P		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220			

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK4D38-20P	6F

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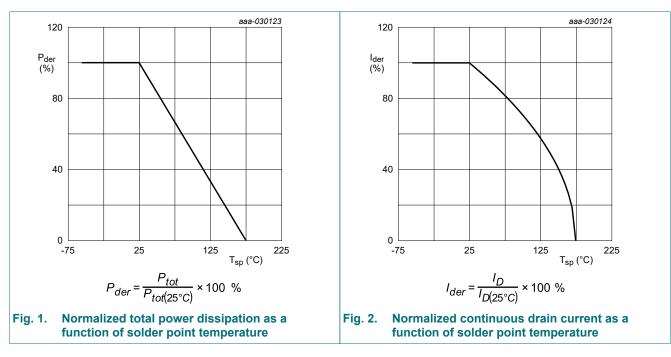
8. Limiting values

Table 5. Limiting values

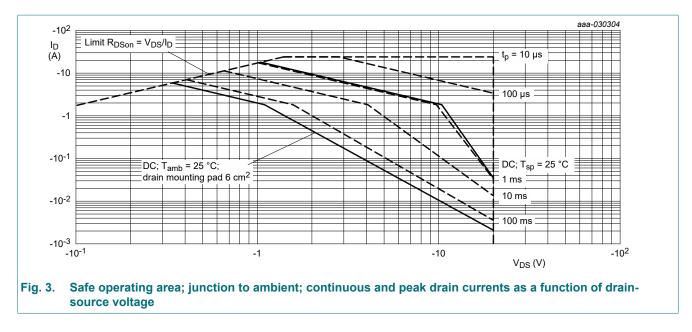
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage	_		-12	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{sp} = 25 °C		-	-18	А
		V _{GS} = -4.5 V; T _{sp} = 100 °C		-	-11	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-6	А
I _{DM}	peak drain current	T_{sp} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-72	А
P _{tot}	total power dissipation	T _{sp} = 25 °C		-	19	W
		T _{amb} = 25 °C	[1]	-	2	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	n diode					_
I _S	source current	T _{sp} = 25 °C		-	-19	А
		T _{amb} = 25 °C	[1]	-	-2	А
I _{SM}	peak source current	single pulse; $t_p \le 10 \ \mu s$; $T_{sp} = 25 \ ^{\circ}C$		-	-75	А
ESD maximu	um rating					_
V _{ESD}	electrostatic discharge voltage	НВМ	[2]	-	1000	V
Avalanche r	uggedness	•				
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = 1.5 A; DUT in v avalanche (unclamped)		-	15	mJ
		1		I		

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².
 Measured between all pins.



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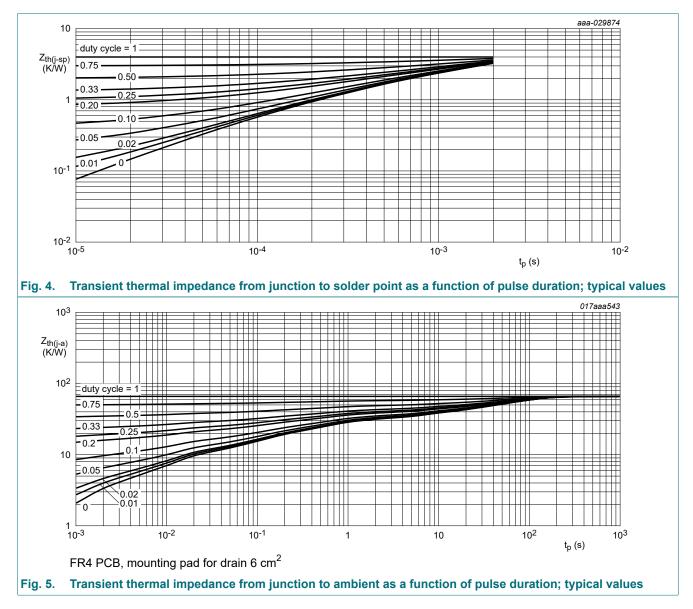


BUK4D38-20P

9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	66	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	8	K/W

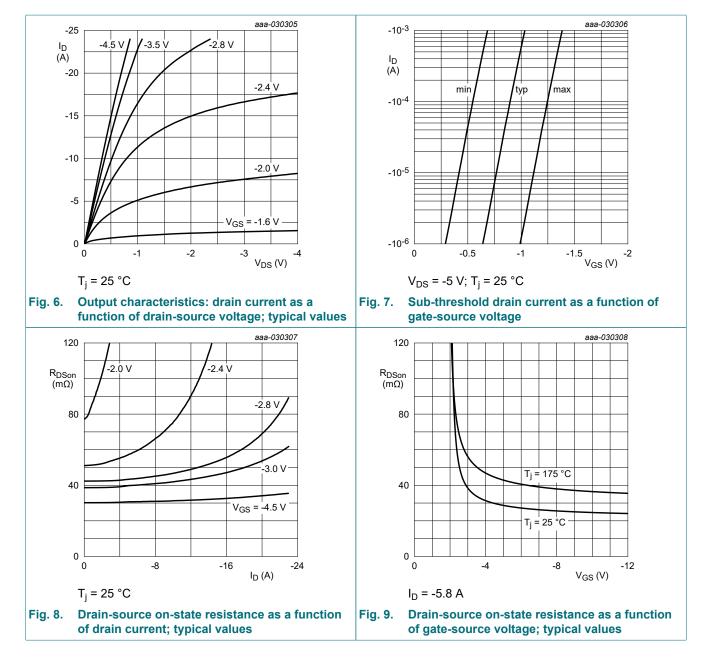
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



10. Characteristics

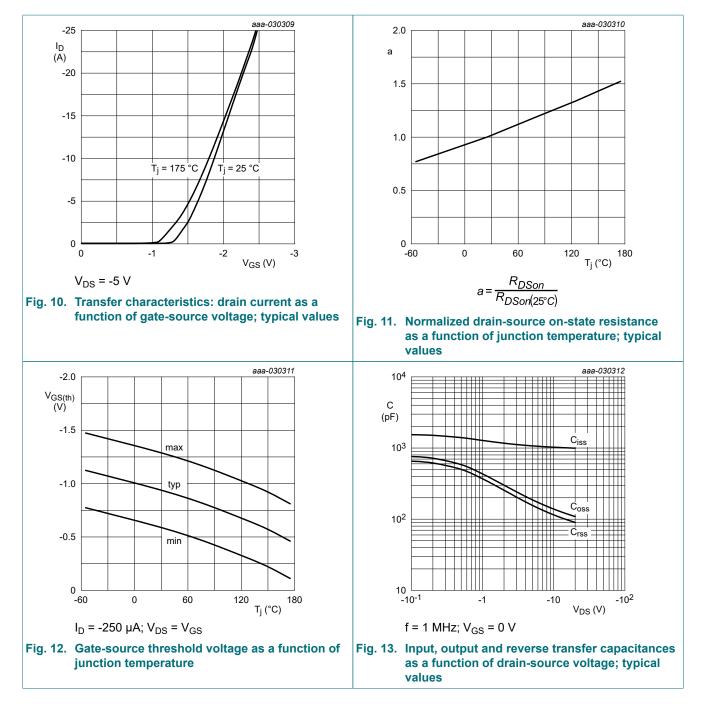
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · ·				
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.6	-0.95	-1.3	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 125 °C	-	-	-20	μA
I _{GSS}	gate leakage current	V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	2	μA
R _{DSon}	drain-source on-state resistance	V _{GS} = -8 V; I _D = -6 A; T _j = 25 °C	-	26	33	mΩ
		V _{GS} = -8 V; I _D = -6 A; T _j = 175 °C	-	40	50	mΩ
		V _{GS} = -4.5 V; I _D = -6 A; T _j = 25 °C	-	30	38	mΩ
		V _{GS} = -2.5 V; I _D = -2 A; T _j = 25 °C	-	46	64	mΩ
9fs	forward transconductance	V _{DS} = -10 V; I _D = -6 A; T _j = 25 °C	-	20	-	S
R _G	gate resistance	f = 1 MHz	-	21	-	Ω
Dynamic ch	naracteristics		I		_	
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -5.8 A; V _{GS} = -4.5 V;	-	10.6	16	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.1	-	nC
Q _{GD}	gate-drain charge		-	3.6	-	nC
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	1025	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	137	-	pF
C _{rss}	reverse transfer capacitance		-	113	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -5.8 A; V _{GS} = -4.5 V;	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	17	-	ns
d(off)	turn-off delay time		-	23	-	ns
t _f	fall time		-	19	-	ns
Source-drai	in diode		I			
V _{SD}	source-drain voltage	I _S = -2 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.8	-1.2	V
t _{rr}	reverse recovery time	$I_{S} = -2 \text{ A}; \text{ d}I_{S}/\text{d}t = 100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	17	-	ns
Q _r	recovered charge	V _{DS} = -10 V; T _j = 25 °C	-	5	-	nC

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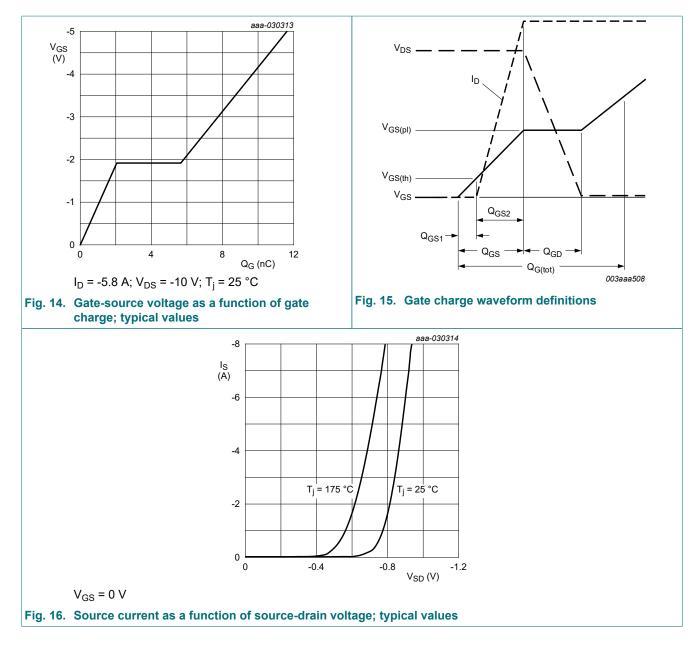


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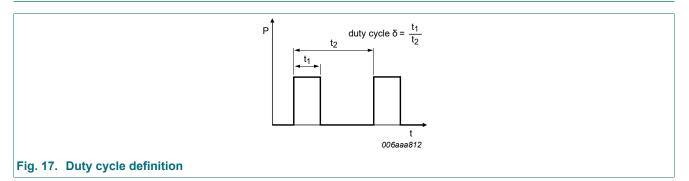
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11. Test information

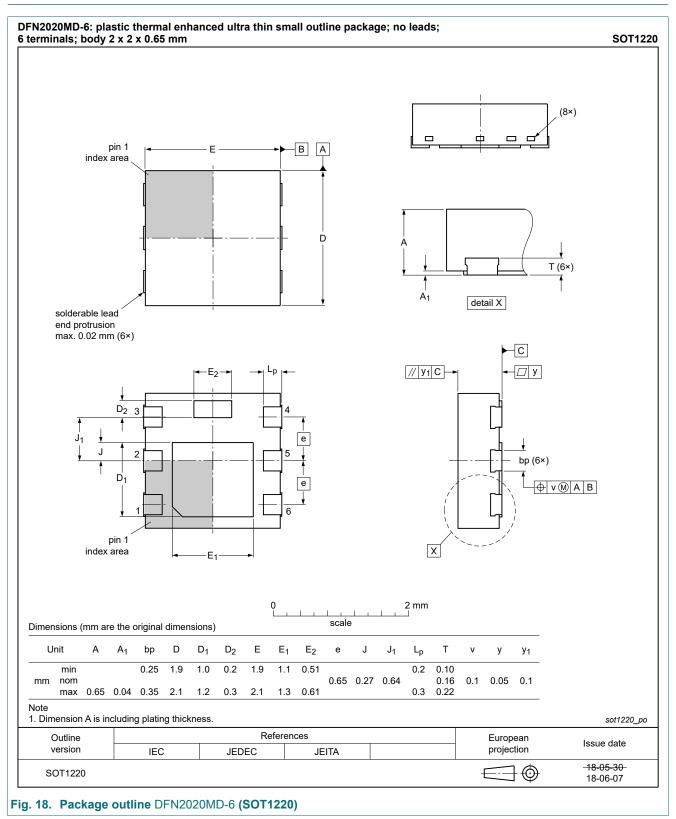


Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

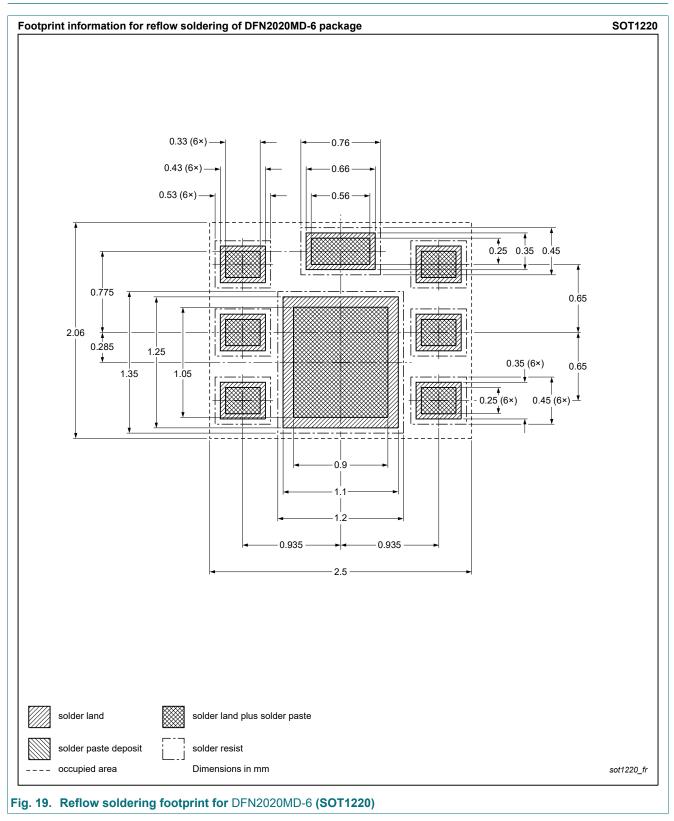
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12. Package outline



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13. Soldering



14. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK4D38-20P v.3	20200709	Product data sheet	-	BUK4D38-20P v.2
Modifications:	Product status	changed.	·	
BUK4D38-20P v.2	20200121	Objective data sheet	-	BUK4D38-20P v.1
BUK4D38-20P v.1	20191025	Objective data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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